





Rev.A Apr.-2022

## 描述

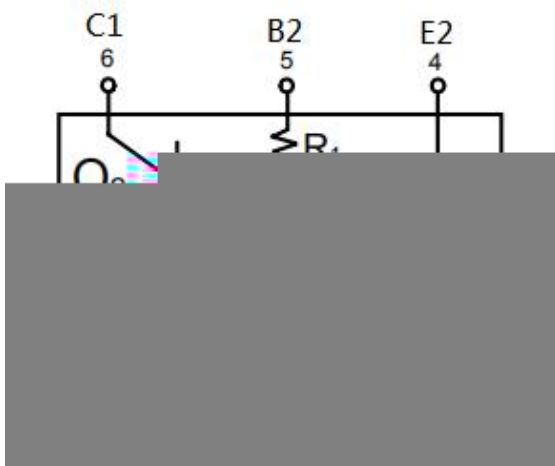
silicon NPN and PNP transistor in a SOT-363 Plastic Package

## 特征

With built-in bias resistors, simplify circuit design, reduce a quantity of parts and manufacturing process, HF Product.

## 用途

Switching applications, interface circuit and driver circuit applications.



## 放大及印章代码

Marking	H335
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Parameter	Symbol	Rating	Unit
Supply Voltage	$V_{CC}$	50	V
Input Voltage	$V_{IN}$	12	V
		-5	V
Output Current	$I_O$	100	mA
Collector Dissipation	$P_C$	187	mW
Junction Temperature	$T_j$	150	
Storage Temperature Range	$T_{stg}$	-55~150	

Parameter                      Symbol

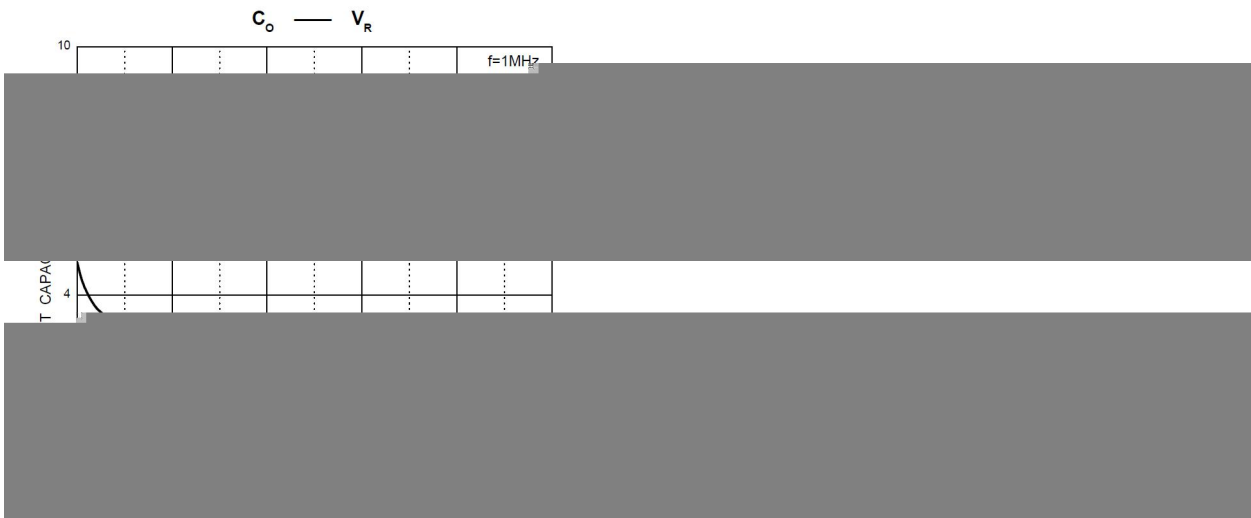
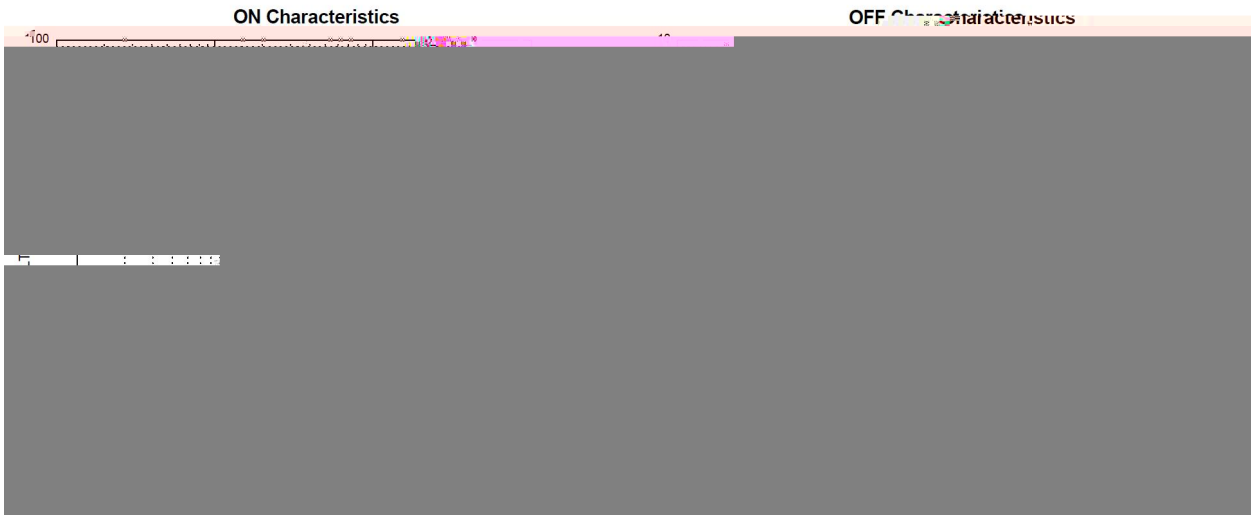


Parameter	Symbol	Rating	Unit
Supply Voltage	$V_{CC}$	-50	V
Input Voltage	$V_{IN}$	-12	V
		5	V
	$I_o$	-100	mA

Power Dissi

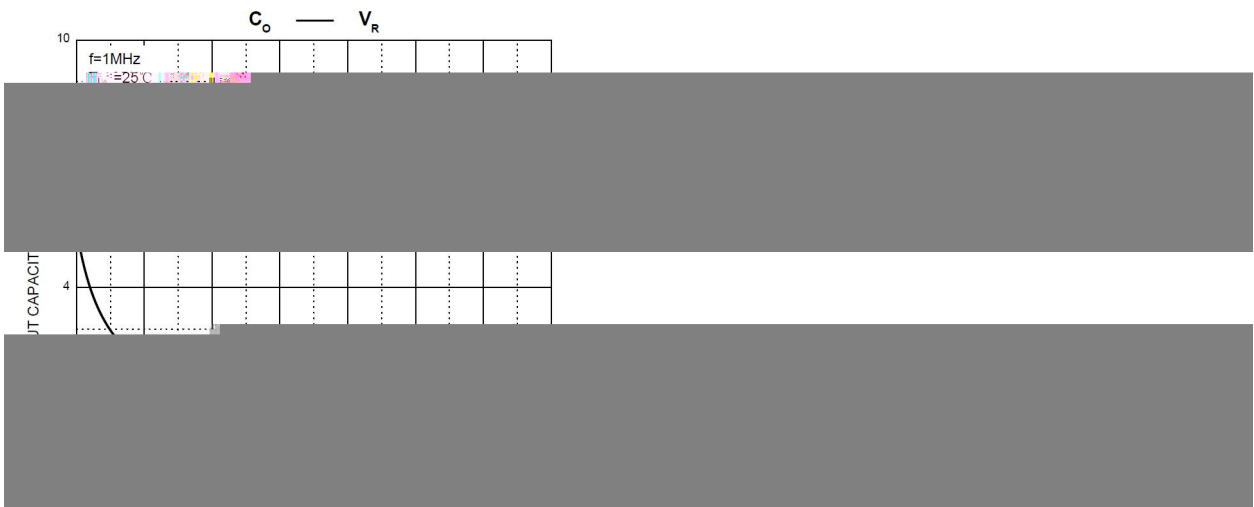
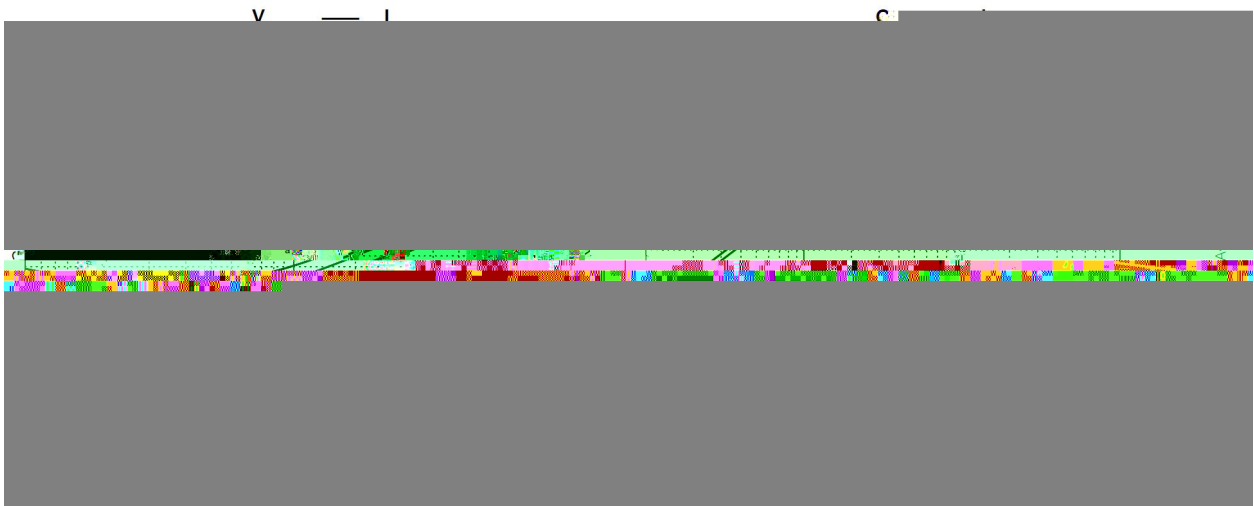
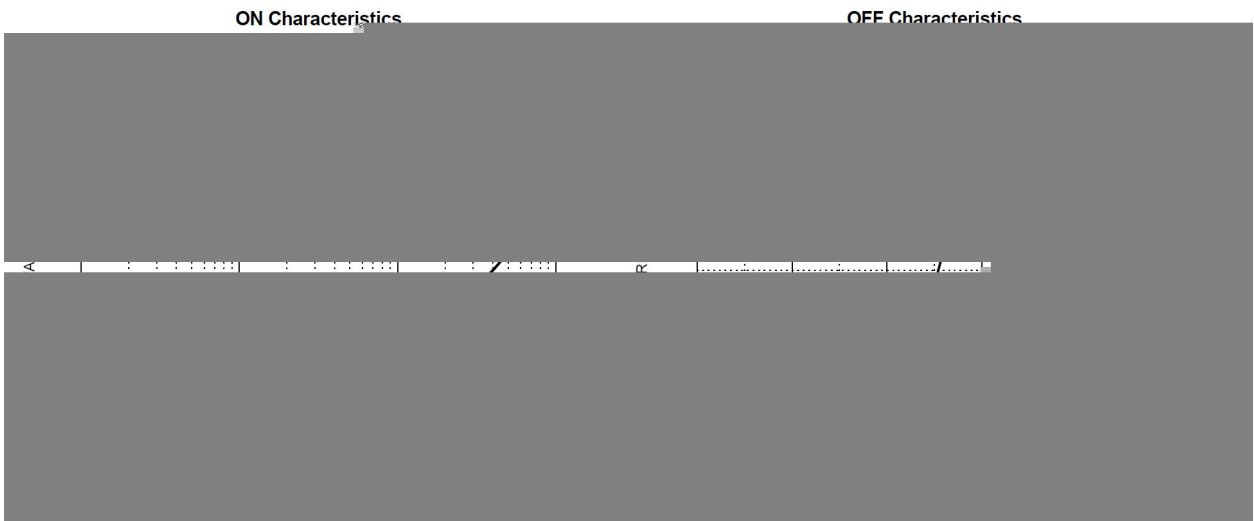


电参数曲线图



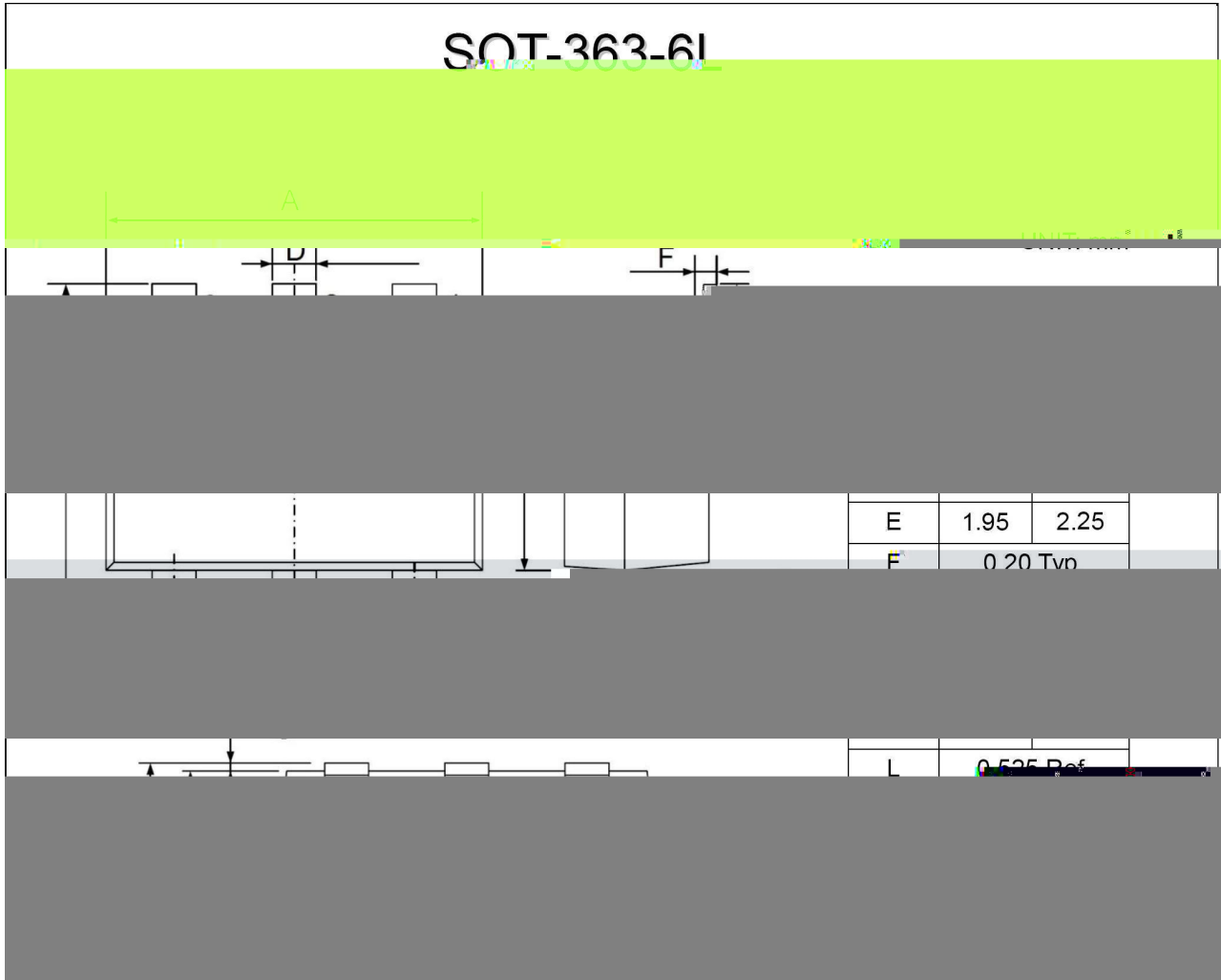


电参数曲线图





外形尺寸图



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回流焊温度曲线图 无铅 Temperature Profile for IR Reflow Soldering (Pb-Free)


Note:

- 1 150 180 60 90sec;
- 2 245 5 5 0.5sec;

1.Preheating:150~180 , Time:60~90sec.